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2SK2596

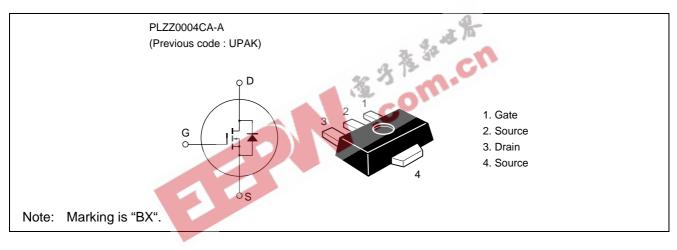
Silicon N-Channel MOS FET UHF Power Amplifier

REJ03G0207-0300 (Previous ADE-208-1367(Z)) Rev.3.00 Feb.14.2005

Features

- High power output, High gain, High efficiency $PG = 12.2 \ dB, Pout = 30.2 \ dBm, \eta D = 45\% min. \ (f = 836.5 \ MHz)$
- Compact package capable of surface mounting

Outline



This Device is sensitive to Electro Static Discharge. An Adequate handling procedure is requested.

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	17	V
Gate to source voltage	V _{GSS}	±10	V
Drain current	ID	0.4	A
Drain peak current	I _{D(pulse)} Note1	1	A
Channel dissipation	Pch Note2	3	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-45 to +150	°C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = 25°C

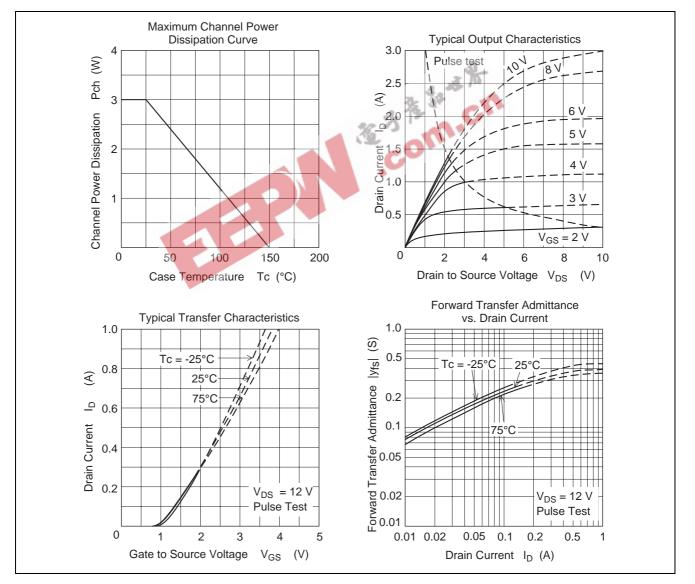


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Electrical Characteristics

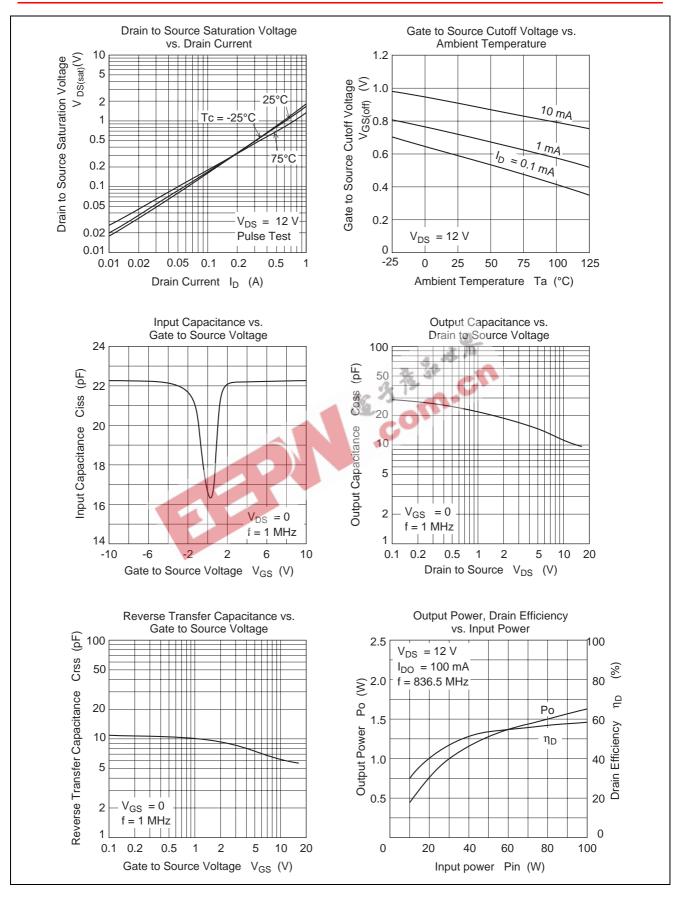
 $(Ta = 25^{\circ}C)$ **Test Conditions** Item Symbol Min. Max. Unit Тур 10 $V_{DS} = 12 V, V_{GS} = 0$ Zero gate voltage drain current μΑ IDSS Gate to source leak current ±5.0 $V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$ I_{GSS} μΑ Gate to source cutoff voltage 0.4 1.1 V $I_D = 2 \text{ mA}, V_{DS} = 12 \text{ V}$ V_{GS(off)} Input capacitance $V_{GS} = 5 V, V_{DS} = 0, f = 1 MHz$ Ciss 22 pF pF $V_{DS} = 12 V, V_{GS} = 0, f = 1 MHz$ Output capacitance Coss 10.5 ____ _ Output Power 30.2 dBm V_{DS} = 12 V, f = 836.5 MHz Pout 31.46 Pin = 18 dBm Drain Efficiency 45 55 % V_{DS} = 12 V, Pout = 30.2 dBm ηD f = 836.5 MHz, Pin = 18 dBm

Main Characteristics





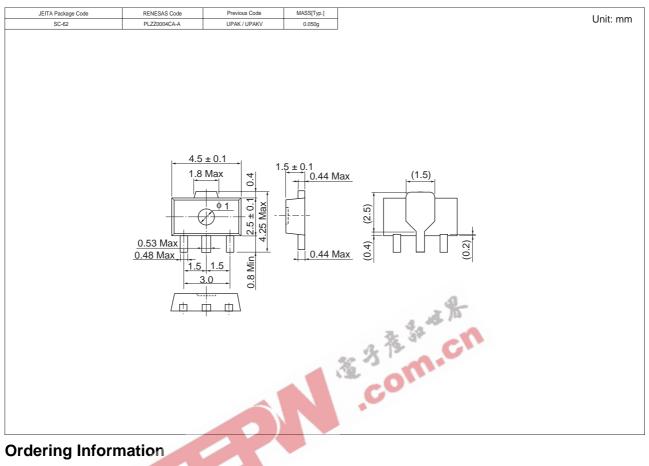
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Package Dimensions



Part Name		Quantity	Shipping Container
2SK2596BX	1000		φ178 taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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